NSN 5962-01-393-4751

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View Online at https://aerobasegroup.com/nsn/5962-01-393-4751
Body Length:
0.440 inches
Body Width:
Between 0.045 inches and 0.085 inches
Body Height:
Between 0.045 inches and 0.085 inches
Maximum Power Dissipation Rating:
100.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Bipolar and monolithic and schottky and electrostatic sensitive and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
F-5 mil-m-38510
Current Rating Per Characteristic:
130.00 milliamperes reverse current, dc minor
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, schottky ttl, 256 x 4 bit programmed prom, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, high to low level output and 20.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom

Special Features:

Electrostatic discharge sens; altered item, made from m38510/20304bfa, software file number 8907815-14-791, model

cpu/rc-8905830-501, location u330

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Test	Data	Docum	ent
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0